



## TRI-STATE BUFFER

**■ GENERAL DESCRIPTION**

The NJU6342 Series is a tri-state buffer which is input the external ECL oscillation signal and output C-MOS level signal.

It consists of an amplifier and tri-state output buffer.

The input/output frequency is as wide as up to 120MHz and the symmetry of 45-55% is realized over full operating frequency range.

NJU6342H is TTL compatible and capable of 5 TTL driving.

NJU6342 is FACT equivalent.

**■ PACKAGE OUTLINE**

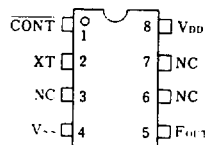
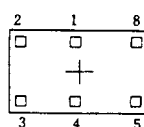

NJU6342XC



NJU6342XE

**4**
**■ FEATURES**

- Operating Voltage -- 4.0~6.0V
- Maximum Oscillation Frequency -- 120MHz
- Low Operating Current
- High Fan-out NJU6342 : FACT equivalent  
NJU6342H: 5TTL
- 3-state Output Buffer
- Output Stand-by Function
- Package Outline -- CHIP/EMP 8
- C-MOS Technology

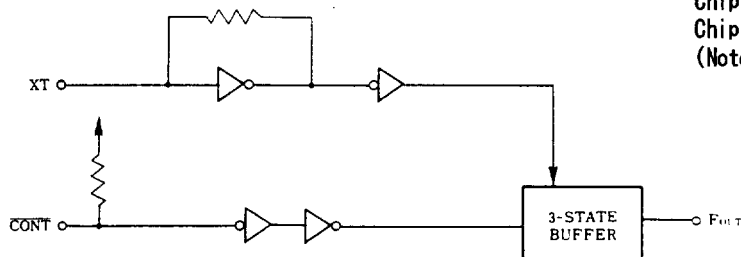
**■ PIN CONFIGURATION/PAD LOCATION**

**■ LINE-UP TABLE**

VERSION	Fan-out
NJU6342	FACT equivalent( $I_{OL}/I_{OH}=24mA$ )
NJU6342H	5TTL

**■ COORDINATES**

 Unit:  $\mu m$ 

No.	PAD	X	Y
1	CONT	- 29	181
2	XT	- 462	181
3	NC	- 463	- 181
4	VSS	- 44	- 229
5	FOUT	564	- 229
8	VDD	564	229

**■ BLOCK DIAGRAM**


Chip Size : 1.49 X 0.8mm  
 Chip Center :  $X=0\mu m, Y=0\mu m$   
 Chip Thickness :  $400\mu m \pm 30\mu m$   
 (Note) No. 6 and 7 terminals are only for package type information. There are no PAD on the chip.


**TERMINAL DESCRIPTION**

NO.	SYMBOL	FUNCTION	
1	CONT	Tri-state output control terminal	
		CONT	F <sub>OUT</sub>
		H or OPEN	Input ECL oscillation signal output
		L	Output High Impedance
2	XT	External ECL oscillation signal input terminal	
4	V <sub>SS</sub>	GND	
5	F <sub>OUT</sub>	Output amplified external ECL oscillation frequency	
8	V <sub>DD</sub>	+ 5V	

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**ABSOLUTE MAXIMUM RATINGS**

(Ta=25°C)

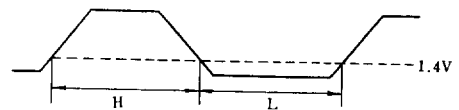
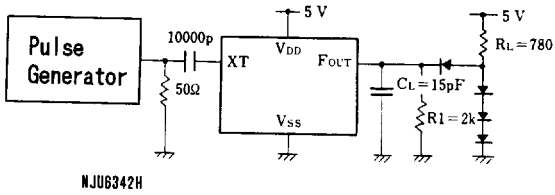
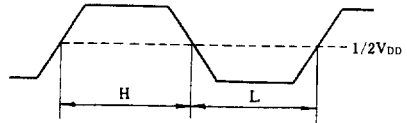
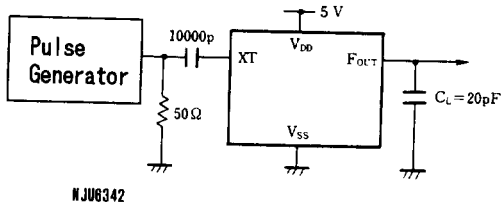
PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V <sub>DD</sub>	- 0.3 ~ +7.0	V
Input Voltage	V <sub>IN</sub>	V <sub>SS</sub> -0.3 ~ V <sub>DD</sub> +0.3	V
Output Voltage	V <sub>O</sub>	- 0.5 ~ V <sub>DD</sub> +0.5	V
Input Current	I <sub>IN</sub>	±10	mA
Output Current	I <sub>O</sub>	±25	mA
Power Dissipation (EMP)	P <sub>D</sub>	200	mW
Operating Temperature Range	T <sub>opr</sub>	- 30 ~ + 75	°C
Storage Temperature Range	T <sub>stg</sub>	- 40 ~ +125	°C

**ELECTRICAL CHARACTERISTICS**

 (Ta=25°C, V<sub>DD</sub>=5V)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT	
Operating Voltage	V <sub>DD</sub>		4		6	V	
Operating Current	I <sub>DD</sub>	f <sub>IN</sub> =120MHz, V <sub>IN</sub> =0.5V <sub>P-P</sub> Sine wave input, No load			65	mA	
Stand-by Current	I <sub>st</sub>	CONT=XT=V <sub>SS</sub> , No load (Note)			1	μA	
Input Voltage	V <sub>IH</sub>	CONT Terminal	4.5		5.0	V	
	V <sub>IL</sub>		0		0.5		
Output Current	I <sub>OH</sub>	V <sub>OH</sub> =4.5V	NJU6342	24		mA	
			NJU6342H	4			
	I <sub>OL</sub>	V <sub>OL</sub> =0.5V	NJU6342	24			
			NJU6342H	8			
Input Current	I <sub>IN</sub>	CONT Terminal, CONT=V <sub>SS</sub>	125	250	500	μA	
Tri-state Off-leakage Current	I <sub>oz</sub>	CONT=V <sub>SS</sub> , F <sub>OUT</sub> =V <sub>DD</sub> or V <sub>SS</sub>			±1	μA	
Max. Operating Frequency	f <sub>MAX</sub>		120			MHz	
Input Oscillation Swing	V <sub>IN</sub>	C <sub>IN</sub> =10000pF, f <sub>IN</sub> =120MHz Sine wave input	0.5			V <sub>P-P</sub>	
Output Signal Symmetry	SYM	C <sub>L</sub> =20pF @1/2V <sub>DD</sub> f <sub>IN</sub> =120MHz V <sub>IN</sub> =0.5V <sub>P-P</sub>	NJU6342	45	50	55	%
		C <sub>L</sub> =15pF, R <sub>L</sub> =780Ω @1.4V f <sub>IN</sub> =120MHz V <sub>IN</sub> =0.5V <sub>P-P</sub>	NJU6342H	45	50	55	
Output Signal Rise Time	t <sub>r</sub>	C <sub>L</sub> =20pF, R <sub>L</sub> =450Ω 20%~80%	NJU6342		0.8		ns
		C <sub>L</sub> =15pF, R <sub>L</sub> =780Ω 0.4V~2.4V	NJU6342H		1.4		
Output Signal Fall Time	t <sub>f</sub>	C <sub>L</sub> =20pF, R <sub>L</sub> =450Ω 80%~20%	NJU6342		0.8		
		C <sub>L</sub> =15pF, R <sub>L</sub> =780Ω 2.4V~0.4V	NJU6342H		0.8		

Note ) Excluding input current on CONT terminal.


**MEASUREMENT CIRCUITS**
**(1) Output Symmetry**

**(2) Output Rise / Fall Time**
